TOSHIBA Bipolar Linear IC Silicon Monolithic

TA2131FN

Low Current Consumption Headphone Amplifier for Portable MD Player (With Bass Boost

The TA2131FN is a low current consumption headphone amplifier developed for portable digital audio. It is particularly well suited to portable MD players that are driven by a single dry cell. It also features a built-in bass boost function with AGC, and is capable of bass amplification of DAC output and analog signals such as tuner.

Features

- Low current consumption: I_{CCQ} (V_{CC1}) = 0.55 mA (typ.) I_{CCQ} (V_{CC2}) = 0.20 mA (typ.)
- Output power: $P_0 = 8 \text{ mW}$ (typ.) (V_{CC1} = 2.8 V, V_{CC2} = 1.2 V, f = 1 kHz, THD = 10%, R_L = 16 Ω)
- Low noise: $V_{no} = -102 dBV$ (typ.)
- Built-in low-pass boost (with AGC)
- I/O pin for beep sound
- Outstanding ripple rejection ratio
- Built-in power mute
- Built-in power ON/OFF switch
- Operating supply voltage range (Ta = 25° C): V_{CC1} = $1.8 \sim 4.5$ V

 $\mathrm{V}\mathrm{C}\mathrm{C}\mathrm{2}=0.9{\sim}4.5~\mathrm{V}$



Weight: 0.14 g (typ.)

Block Diagram



Terminal Explanation (Terminal voltage: Typical terminal voltage at no signal with test circuit, $V_{CC1} = 2.8$ V, $V_{CC2} = 1.2$ V, Ta = 25°C)

	Te	erminal No.	Terminal Explanation	Internal Circuit	
www.datas	heet4ı 1	I.COM LPF ₂	BST amplifier 1 output (filter terminal)	$\begin{array}{c} PW_{A} \\ 12 \\ 20 \\ k\Omega \\ \hline \end{array} \\ \end{array} \\ \begin{array}{c} ADD \\ \hline \\$	0.61
	23	LPF ₁	ADD amplifier output (filter terminal)	$\begin{array}{c} 20 \text{ k}\Omega \\ 13 \text{ PW}_{\text{B}} \end{array}$	0.61
	24	BST NF1	BST amplifier 1 NF	$\begin{array}{c c} & & & & \\ & & & & \\ & & & & \\ & & & & $	0.61
	2	BST NF ₂	BST amplifier 2 NF terminal (low-pass compensation condenser connection terminal)		0.61
	3	BST OUT	BST amplifier 2 output terminal		
	6	OUTB	Power amplifier	$\begin{array}{c c} BST1 & 10 \ k\Omega & 15 \ k\Omega \\ \hline OUT & G \\ BST_2 & G \\ BST_2 & G \\ \hline \end{array} $	0.61
	8	OUT _A	ουτρυτ	$\begin{array}{c} \begin{array}{c} \begin{array}{c} \\ \\ \\ \\ \\ \\ \\ \\ \\ \\ \\ \\ \\ \\ \\ \\ \\ \\ \\$	
	12	INĄ	Power amplifier input		0.61
	13	IN _B			

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	Terminal No.		Terminal Explanation	Internal Circuit	
www.datas	heet4u 4	I.com AGC IN	com Signal input level to BST amplifier is varied according to the input level to the boost AGC input terminal. Input impedance: 15 kΩ (typ.)		0.61
	5	DET	Smoothing of boost AGC level detection		_
	7	PWR GND	GND of power amplifier output stage	_	0
	9	V _{CC2}	V _{CC} (+B) at power amplifier output stage	—	1.2
	10	BEEP OUT _A	Beep sound output		_
	11	BEEP OUT _B	terminal		
	19	BEEP IN	Beep sound input terminal Receives beep sound signals from microcomputer.		0
	14	V _{CC1}	Main V _{CC}		2.8
	15	MT TC	Mute smoothing Power mute switch Reduces the shock noise during switching		1.2

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Termin		erminal No.	Terminal Internal Circuit Explanation		
www.datas	neet4i 16	I.COM PW SW	Power ON/OFF switch "H" level: IC operation "L" level: IC OFF Refer to function explanation 5	V_{CC1} f f f f f f f f	
	17	MT SW	Mute switch "L" level: mute reset "H" level: mute ON Refer to function explanation 5	V_{CC1}	_
	18	BST SW	Bass boost ON/OFF switch "H" level/OPEN: BST ON "L" level: BST OFF Refer to function explanation 5		
	20	GND	GND of input stage in power amplifier	—	0
	21	V _{ref} IN	Reference voltage circuit filter terminal		0.61
	22	V _{ref}	Reference voltage circuit		0.61

Function Explanation

1. Bass Boost Function

1-1 **Description of Operation**

TA2131FN has a bass boost function for bass sound reproduction built-in to the power amplifier. With the bass boost function, at medium levels and lower, channel A and channel B are added for the www.datasheet4u.com low frequency component, and output to BST amplifier 2 (BST2) in negative phase. That signal is inverted and added before being subjected to bass boost. If the signal of the low-frequency component reaches a high level, the boost gain is controlled to main a low distortion (see Fig.1).



System Diagram of Bass Boost Figure 1

1-2 **AGC Circuit**

The AGC circuit of the bass boost function detects with "AGC DET" the voltage component created by "BST₂," and as the input level increases, the variable impedance circuit is changed, and the bass boost signal is controlled so that it is not assigned to BST amplifier 1. In this way, the bass signal to "BST2" input is shut-off, and that boost gain is controlled.

1-3 **Bass Boost System**

As shown in Fig.1, the flow of the bass boost signal is that the signal received from power amplifier input goes through LPF1, ADD amplifier, ATT (variable impedance circuit), BPF1 (BST amplifier 1) and LPF₂, and the negative phase signal to the power amplifier input signal is output from BST amplifier 2. The reason why it becomes the negative phase of the BST amplifier 2 signal is that the phase is inverted by 180° in the audible bandwidth by the secondary characteristics of LPF1 and LPF₂ in Fig.1.

Ultimately the main signal and the bass boost signal formed before BST2 are added. Fig.2 shows the frequency characteristics to each terminal.



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Figure 2 During Bass Boost (Frequency Characteristics to Each Terminal)

2. Low-Pass Compensation

2-1. Function

In C-couple type power amplifiers, it is necessary to give the output condenser C a large capacity to flatten out the frequency characteristics to the low frequency band (this is because the loss in the low frequency bandwidth becomes larger due to the effect of the high-pass filter comprising C and RL). Particularly when the headphone load is approximately 16 Ω and an attempt is being made to achieve frequency characteristics of ±3 dB at 20 Hz, a large capacity condenser of C = 470 μ F is required. Bearing this situation in mind, a low-pass compensation function was built in to the TA2131FN, and while reducing the capacity of the output coupling condenser, almost flat (±3 dB) frequency characteristics in all audible bandwidths (20 Hz to 20 kHz) have been achieved.

Fig.3 shows the low-pass system diagram, and Fig.4 shows the frequency characteristics at each point. In Fig.4, (a) represents the status lost by the low-pass as a result of the high-pass filter comprising the headphone load ($R_L = 16 \Omega$) and the output coupling condenser (220 µF) in the C-coupling system.



Figure 3 Low-Pass Compensation System Diagram



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Figure 4 Power Amplifier Frequency Characteristics

<Principle of Low-Pass Compensation>

The low-pass component alone is extracted from the composite signal of PW_A/PW_B output, and that frequency signal is fed back to PW_A/PW_B once more via the inversion amplifier, thereby making it possible to increase the gain only of the low-pass component. The frequency characteristics of the power amplifier output V (OUT) in this state are shown in Fig.4 (b). In practice they are the frequency characteristics (c) viewed from load terminal V (R_L), and the low-pass is compensated relative to the state in (a).

2-2. Low-Pass Compensation Condenser and Crosstalk

In this low-pass compensation condenser circuit, processing is carried out using the composite signal of power amplifier output, so this affects crosstalk, according to the amount of compensation. f characteristics and crosstalk generated by the capacity of the condenser for compensation (2-pin) are shown below.



Figure 5 Condenser and f Characteristics for Low-Pass Compensation

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Figure 6 Low-Pass Compensation Condenser and Crosstalk

3. Beep

Beep sound signals from microcomputer can be received by the beep input terminal (19-pin). The PW_A and PW_B of the power amplifier during power mute are turned OFF, and the beep signal input from BEEP-IN (19-pin) is output from the BEEP-OUT terminal (10/11-pin) as fixed current, after passing through the converter and current amplification stage. Connecting this terminal to the headphone load outputs the beep sound.

If the beep sound is not input, fix the BEEP-IN (19-pin) terminal to GND level.



4. Power Switch

As long as the power switch is not connected to "H" level, the IC does not operate. If it malfunctions due to external noise, however, it is recommended to connect a pull-down resistor externally (the power switch is set to be highly sensitive).



www.datash5et4u.cThreshold Voltages of Switches

6. These capacitors which prevent oscillation of the power amplifier, and are between the V_{ref} and V_{CC} -GND must have a small temperature coefficient and outstanding frequency characteristics.

BST SW (V18)

BST ON

BST OFF

"H" level/OPEN

"L" level

Maximum Ratings

	Characteristic	Symbol	Rating	Unit
www.datas	Supply voltage	V _{CC} 4.5		V
	Output current	I _{o (peak)}	100	mA
	Power dissipation	P _D (Note)	500	mW
	Operating temperature	T _{opr}	-25~75	°C
	Storage temperature	T _{stg}	-55~150	°C

Note: Derated above $Ta = 25^{\circ}C$ in the proportion of 4 mW/°C.

Electrical Characteristics (Unless specified otherwise, $V_{CC1} = 2.8$ V, $V_{CC2} = 1.2$ V, $R_g = 600 \ \Omega$, $R_L = 16 \ \Omega$, f = 1 kHz, $Ta = 25^{\circ}$ C)

	Characteristic	Symbol	Test condition	Min	Тур.	Max	Unit	
		I _{CC1}	IC OFF (V _{CC1}), SW1: b, SW2: b	—	0.1	5	μА	
		I _{CC2}	IC OFF (V _{CC2}), SW1: b, SW2: b	_	0.1	5		
Ouiz	scont supply current	I _{CC3}	MUTE ON (V _{CC1}), SW1: a, SW2: b	_	0.35	0.50	mA	
Quiescent supply current		I _{CC4}	MUTE ON (V _{CC2}), SW1: a, SW2: b	_	5	10	μA	
		I _{CC5}	No signal (V _{CC1}), SW1: a, SW2: a	_	0.55	0.75		
		I _{CC6}	No signal (V _{CC2}), SW1: a, SW2: a	_	0.20	0.40	~ ^	
Pow	er supply current during	I _{CC7}	$P_o = 0.5 \text{ mW} + 0.5 \text{ mW} \text{ output } (V_{CC1})$	_	0.6	_	ША	
drive	9	I _{CC8}	$P_0 = 0.5 \text{ mW} + 0.5 \text{ mW} \text{ output } (V_{CC2})$	_	5.3	_		
	Gain	GV	$V_0 = -22 dBV$	10	12	14	dB	
	Channel balance	СВ	$V_0 = -22 dBV$	-1.5	0	1.5		
	Output power	Pomax	THD = 10%	5	8	_	mW	
	Total harmonic distortion	THD	P _o = 1 mW	_	0.1	0.3	%	
tion	Output noise voltage	V _{no}	$R_g = 600 \Omega$, Filter: IHF-A, SW4: b	_	-102	-96	dBV	
Sec	Crosstalk	СТ	$V_0 = -22 dBV$	-42	-48	_	dB	
Power		RR1	$f_r = 100 \text{ Hz}, V_r = -20 \text{dBV}$ inflow to V_{CC2}	-71	-77			
		RR2	$f_r = 100 \text{ Hz}, V_r = -20 \text{dBV}$ inflow to V _{CC1}	-54	-64	_		
	Mute attenuation	ATT	$V_0 = -12$ dBV, SW2: a \rightarrow b	-90	-100	_		
	Beep sound output voltage	VBEEP	V Beep IN = 2 V_{p-0} , SW2: b	-53	-48	-43	dBV	
Boost gain		BST1	$V_0 = -20$ dBV, f = 100 Hz, SW3: ON \rightarrow OPEN	1	4	7	dB	
		BST2	$V_0 = -30$ dBV, f = 100 Hz, SW3: ON \rightarrow OPEN	10	13	16		
		BST3	$V_0 = -50 dBV$, f = 100 Hz, SW3: ON \rightarrow OPEN	13.5	16.5	19.5		

Test Circuit



(*) $0.22 \ \mu F + 10 \ \Omega$ Monolithic ceramic capacitor

Application Circuit 1



(*) $0.22 \ \mu F + 10 \ \Omega$ Monolithic ceramic capacitor

Application Circuit 2 (Low-Pass Compensation/Bass Boost Function/Beep Not Used)



(*) $0.22 \ \mu F + 10 \ \Omega$ Monolithic ceramic capacitor

Characteristics (Unless otherwise specified V_{CC1} = 2.8 V, V_{CC2} = 1.2 V, R_g = 600 Ω , f = 1 kHz, Ta = 25°C) $V_{DC} - V_{CC2}$ (V_{ref}, OUT)











0.3

Output voltage Po

3

(mW)

1

10

30

(mA)

<u>0</u>

Consumption supply current

0.1 0.01

0.03

0.1



15





 $\mathsf{THD} - \mathsf{V}_{\mathsf{CC2}}$ 30 $R_L = 16 \Omega$ $P_0 = 1 \text{ mW}$ (%) 10 A/Bch IN Total harmonic distortion THD 10.02 0.3 10 († 100 Hz 0.1 kHz 0.03**L** 0.6 0.8 1.2 2.0 2.2 2.4 1.6 1.8 1.0 1.4 Supply voltage V_{CC2} (V)















Package Dimensions



Weight: 0.14 g (typ.)

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